NSN 5961-01-208-5102

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-208-5102 **Inclosure Material:** Metal **Overall Length:** 4.799 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, peak and 140.0 reverse voltage, total rms **Current Rating Per Characteristic:** 150.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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